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- EPIC™ (Enhanced-Performance Implanted CMOS) 1-µm Process
- Package Options Include Plastic Small-Outline (DW), Shrink Small-Outline (DB), and Thin Shrink Small-Outline (PW) Packages, Ceramic Chip Carriers (FK), Flat (W), and DIP (J, N) Packages

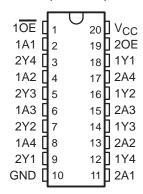
description

These octal buffers and line drivers are designed specifically to improve the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters.

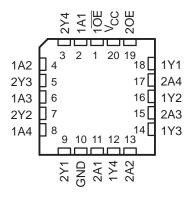
The 'AC241 are organized as two 4-bit buffers/drivers with separate complementary output-enable ($1\overline{OE}$ and 2OE) inputs. When $1\overline{OE}$ is low or 2OE is high, the device passes noninverted data from the A inputs to the Y outputs. When $1\overline{OE}$ is high or 2OE is low, the outputs are in the high-impedance state.

The SN54AC241 is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74AC241 is characterized for operation from –40°C to 85°C.

SN54AC241 . . . J OR W PACKAGE SN74AC241 . . . DB, DW, N, OR PW PACKAGE (TOP VIEW)



SN54AC241 . . . FK PACKAGE (TOP VIEW)



FUNCTION TABLES

INPU	JTS	OUTPUT
10E	1A	1Y
L	Н	Н
L	L	L
Н	Χ	Z

INP	JTS	OUTPUT
20E	2A	2Y
Н	Н	Н
Н	L	L
L	Χ	Z

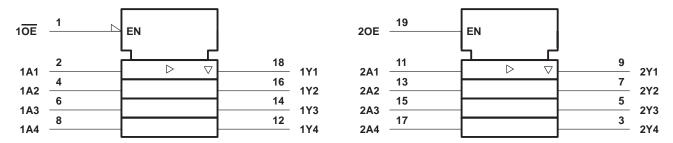


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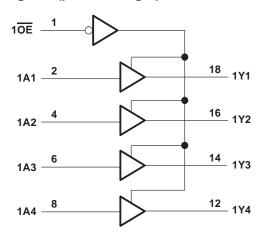


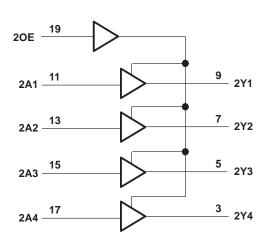
logic symbol[†]



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)





absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage range, V _{CC}	0.5 V to 7 V
Input voltage range, V _I (see Note 1)	0.5 V to V _{CC} + 0.5 V
Output voltage range, VO (see Note 1)	0.5 V to V _{CC} + 0.5 V
Input clamp current, I_{IK} ($V_I < 0$ or $V_I > V_{CC}$)	±20 mA
Output clamp current, I _{OK} (V _O < 0 or V _O > V _{CC})	±20 mA
Continuous output current, I_O ($V_O = 0$ to V_{CC})	±50 mA
Continuous current through V _{CC} or GND	±200 mA
Maximum power dissipation at $T_A = 55^{\circ}C$ (in still air) (see Note 2): Definition of the context of the con	B package 0.6 W
DI	W package1.6 W
N	package 1.3 W
P\	W package 0.7 W
Storage temperature range, T _{stg}	–65°C to 150°C

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.



^{2.} The maximum package power dissipation is calculated using a junction temperature of 150°C and a board trace length of 750 mils, except for the N package, which has a trace length of zero.

recommended operating conditions (see Note 3)

			SN54A	C241	SN74AC241		UNIT
			MIN	MAX	MIN	MAX	UNIT
Vcc	Supply voltage		2	6	2	6	V
		V _{CC} = 3 V	2.1		2.1		
V_{IH}	High-level input voltage	$V_{CC} = 4.5 \text{ V}$	3.15		3.15		V
		$V_{CC} = 5.5 \text{ V}$	3.85		3.85		
V _{IL}		V _{CC} = 3 V		0.9		0.9	
	Low-level input voltage	$V_{CC} = 4.5 \text{ V}$		1.35		1.35	V
	V	$V_{CC} = 5.5 \text{ V}$		1.65		1.65	
VI	Input voltage		0	VCC	0	VCC	V
VO	Output voltage		0	VCC	0	VCC	V
		V _{CC} = 3 V	190	-12		-12	
IOH	High-level output current	$V_{CC} = 4.5 \text{ V}$	7	-24		-24	mA
		$V_{CC} = 5.5 \text{ V}$		-24		-24	
		V _{CC} = 3 V		12		12	
lOL	Low-level output current	$V_{CC} = 4.5 \text{ V}$		24		24	mA
		$V_{CC} = 5.5 \text{ V}$		24		24	
Δt/Δν	Input transition rise or fall rate		0	8	0	8	ns/V
TA	Operating free-air temperature		-55	125	-40	85	°C

NOTE 3: Unused inputs must be held high or low to prevent them from floating.

SN54AC241, SN74AC241 OCTAL BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DA.	DAMETER	TEST CONDITIONS	V	T _A = 25°C			SN54AC241		SN74AC241		UNIT		
PA	RAMETER	TEST CONDITIONS	vcc	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT		
VOH			3 V	2.9			2.9		2.9				
		I _{OH} = -50 μA	4.5 V	4.4			4.4		4.4				
		5.5 V	5.4			5.4		5.4					
	I _{OH} = -12 mA	3 V	2.56			2.4		2.46		J ,,			
		4.5 V	3.86			3.7		3.76		V			
	I _{OL} = -24 mA	5.5 V	4.86			4.7		4.76					
		I _{OH} = -50 mA†	5.5 V				3.85				.		
		I _{OH} = -75 mA [†]	5.5 V						3.85				
			3 V			0.1		0.1		0.1			
		I _{OL} = 50 μA	4.5 V			0.1		0.1		0.1	V		
			5.5 V			0.1		0.1		0.1			
\/a:		I _{OL} = 12 mA	3 V			0.36	3	0.5		0.44			
VOL		lo 24 mA	4.5 V			0.36	90	0.5		0.44	V		
VOL Data inputs	I _{OL} = 24 mA	5.5 V			0.36	d'd	0.5		0.44				
		I _{OL} = 50 mA [†]	5.5 V					1.65					
		I _{OL} = 75 mA [†]	5.5 V		4.4 4.4 4.4 5.4 5.4 5.4 2.56 2.4 2.46 3.86 3.7 3.76 4.86 4.7 4.76 3.85 3.85 3.85 0.1 0.1 0.1 0.1 0.1 0.1 0.1 0.1 0.1 0.1								
١.	Data inputs	V _I = V _{CC} or GND	5.5 V			±0.1		±1		±1	^		
1	Control inputs	V _I = V _{CC} or GND	3.5 V			±0.1		±1		±1	μΑ		
loz		$V_O = V_{CC}$ or GND, $V_{I(OE)} = V_{IL}$ or V_{IH}	5.5 V			±0.25		±5		±2.5	μΑ		
Icc		$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			4		80		40	μΑ		
Ci		V _I = V _{CC} or GND	5 V		2.5						pF		

[†] Not more than one output should be tested at a time, and the duration of the test should not exceed 10 ms.

switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	T _A = 25°C			SN54AC241		SN74AC241		UNIT	
PARAMETER	(INPUT)	(OUTPUT)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT	
t _{PLH}	А	Δ.		1.5	6	9	1	12	1.5	10	ns
^t PHL		ĭ	1.5	6	9	1	11.5	1	10.5	115	
^t PZH	=	Y	1.5	6.5	12.5	-00	13	1	13	no	
^t PZL	OE or OE		1.5	7	12	Q 1.	13	1.5	13	ns	
^t PHZ	OE or OE	0 5 27 05 V	V	2	8	12	1	13	2	12.5	nc
t _{PLZ}	OE OF OE	ſ	1.5	7	12.5	1	13	1	13.5	ns	

switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

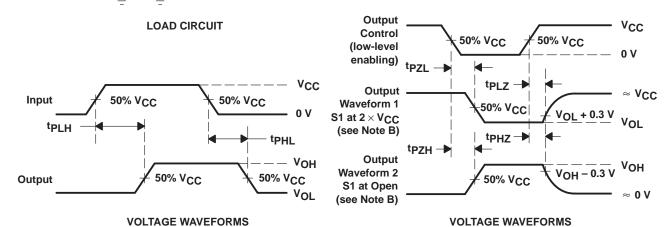
PARAMETER	FROM	то	T _A = 25°C			SN54AC241		SN74AC241		UNIT	
PARAMETER	(INPUT)	(OUTPUT)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT	
tPLH	۸	>	1.5	5	7	1	9.5	1	7.5	ns	
t _{PHL}	A	T	1.5	4.5	7	1	O 9	1	7.5	1115	
^t PZH		V	V	1.5	5.5	9	1	10	1	9.5	no
t _{PZL}	OE or OE	Ĭ	1.5	5.5	9	1	10	1	9.5	ns	
^t PHZ	OE or OE	OF 22 OF	×	1.5	6.5	10	1	11.5	1	10.5	no
tPLZ	OE OF OE	ſ	1.5	6	10	1	11.5	1	10.5	ns	

operating characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$

PARAMETER		TEST CO	TYP	UNIT	
C _{pd}	Power dissipation capacitance per buffer/driver	C _L = 50 pF,	f = 1 MHz	45	pF

PARAMETER MEASUREMENT INFORMATION

From Output Under Test $C_L = 50 \text{ pF}$ (see Note A) S1 Open Open



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, Z_O = 50 Ω , $t_f \leq$ 2.5 ns, $t_f \leq$ 2.5 ns.
- D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



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